TOSHIBA Transistor Silicon NPN Epitaxial Type

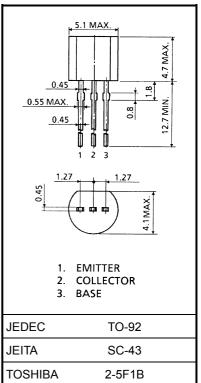
# 2SC2878

#### For Muting and Switching Applications

- High emitter-base voltage:  $V_{EBO} = 25 V (min)$
- High reverse hFE: Reverse hFE = 150 (typ.) (V<sub>CE</sub> = -2 V, I<sub>C</sub> = -4 mA)
- Low on resistance:  $RON = 1 \Omega$  (typ.) (IB = 5 mA)

#### Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V <sub>CBO</sub>	50	V
Collector-emitter voltage	V <sub>CEO</sub>	20	V
Emitter-base voltage	V <sub>EBO</sub>	25	V
Collector current	Ι <sub>C</sub>	300	mA
Base current	Ι <sub>Β</sub>	60	mA
Collector power dissipation	P <sub>C</sub>	400	mW
Junction temperature	Tj	125	°C
Storage temperature range	T <sub>stg</sub>	-55~125	°C



Weight: 0.21 g (typ.)

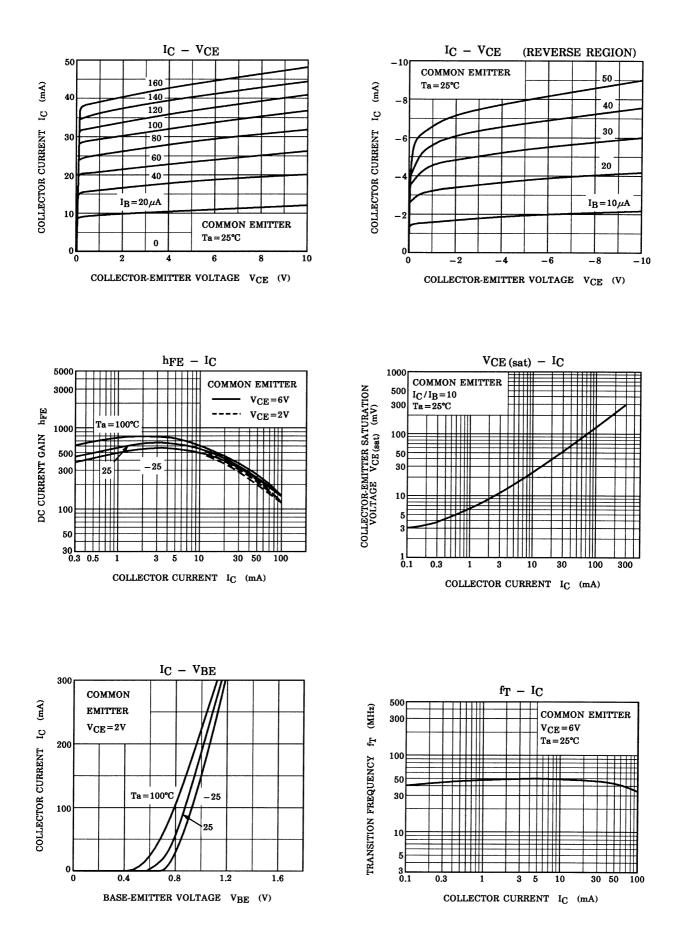
#### **Electrical Characteristics (Ta = 25°C)**

Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off	current	I <sub>CBO</sub>	$V_{CB} = 50 \text{ V}, \text{ I}_{E} = 0$	_		0.1	μA
Emitter cut-off cu	rrent	I <sub>EBO</sub>	$V_{EB} = 25 \text{ V}, \text{ I}_{C} = 0$		_	0.1	μA
DC current gain		h <sub>FE</sub> (Note)	$V_{CE} = 2 V$ , $I_C = 4 mA$	200		1200	
Collector-emitter	saturation voltage	V <sub>CE (sat)</sub>	$I_C = 30 \text{ mA}, I_B = 3 \text{ mA}$		0.042	0.1	V
Base-emitter volt	age	V <sub>BE</sub>	$V_{CE} = 2 V$ , $I_C = 4 mA$		0.61	_	V
Transition frequency		fT	$V_{CE} = 6 \text{ V}, I_C = 4 \text{ mA}$		30	_	MHz
Collector output capacitance		C <sub>ob</sub>	$V_{CB} = 10 \text{ V}, \text{ I}_{E} = 0, \text{ f} = 1 \text{ MHz}$		4.8	7	pF
Switching time	Turn-on time	t <sub>on</sub>	$10V \prod_{\alpha \neq s} VBB VCC = -3V = 12V$	_	160	_	
	Storage time	t <sub>stg</sub>		_	500	_	ns
	Fall time	t <sub>f</sub>			130	_	

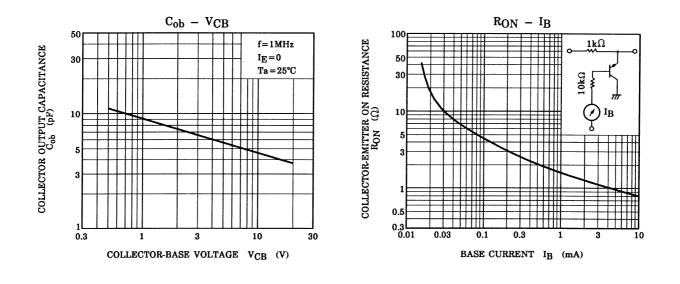
Note: hFE classification A: 200~700, B: 350~1200

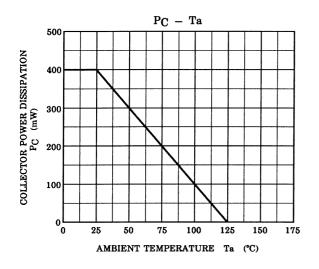
Unit: mm

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